Speech network for telephones BA8216

The BA8216 is a speech network IC which possesses the basic functions required for handset communications. In addition to amplifying signals from a transmitter and sending them to a telephone line, it also amplifies only reception signals from a telephone line and drives the receiver.

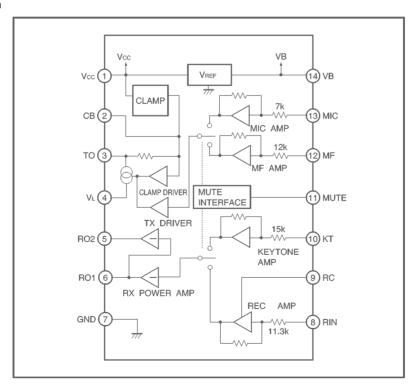
Applications

Telephones and telephone equipment

Features

- 1) Basic speech network functions built in.
 - · Handset transmit and receive circuits
 - DTMF transmit circuit
 - · Key tone input circuit
 - · Mute control and side tone masking circuits
- 2) Can be used with $1.3 k\Omega$ loop circuit resistance and 100Ω telephone resistance.
- A BTL circuit is used for reception output, providing a wide dynamic range which enables use of a ceramic receiver.
- 4) Few external components required.
- 5) 14-pin DIP package.

Block diagram



●Absolute maximum ratings (Ta = 25°C)

| Parameter | Symbol | Limits | Unit |
|-----------------------|----------------|------------------|------|
| Applied voltage | V∟ | 18 | V |
| Current dissipation | l _L | 135 | mA |
| Power dissipation | Pd | 900* | mW |
| Operating temperature | Topr | −25~+75 | °C |
| Storage temperature | Tstg | −55∼ +125 | °C |

^{*} Reduced by 9 mW for each increase in Ta of 1℃ over 25℃.

ullet Electrical characteristics (unless otherwise noted, Ta = 25 $^{\circ}$ C, S₁ = 1, S₂ =1, f = 1kHz, BPF = 400Hz to 30kHz)

| Parameter | | Symbol | Min. | Тур. | Max. | Unit | IL (mA) | Conditions | Measurement circuit | | |
|---------------------------|---------|-----------------|------------------|-------|-------------|------|---------|--|--|----------|--|
| Line voltage (20) | | | V _{L20} | 3.8 | 4.15 | 4.5 | ٧ | 20 | | | |
| Line voltage (120) | | | VL120 | 4.1 | 4.6 | 5.5 | ٧ | 120 | | Fig.11 | |
| Input high level voltage | | | Vıн | 0.8 | _ | _ | ٧ | 40 | S ₂ =2 | | |
| Input low level voltage | | | VIL | _ | _ | 0.5 | ٧ | 40 | S ₂ =2 | | |
| Input high level current | | Ін | 100 | 200 | 300 | μΑ | 40 | S ₂ =2, V _{IH} =4V | | | |
| Electromagnetic | و | Gain | GRD | -13.8 | -10.8 | -7.8 | dB | 40 | V⊤=20dBV | F: 40 | |
| | Receive | Maximum output | V _{RD} | -19 | -15 | _ | dBV | 20 | THD=5% | Fig.12 | |
| | - E | Input impedance | ZRIN | 8.3 | 11.3 | 14.3 | kΩ | 40 | | | |
| | | Gain | Gктр | 10.5 | 13.5 | 16.5 | dB | 40 | S ₂ =3, V _{KT} =-40dBV | Fig.12 | |
| | KT | Maximum output | VKTD | -19 | — 15 | _ | dBV | 20 | S ₂ =3, THD=5% | | |
| | | Input impedance | Zĸт | 11 | 15 | 19 | kΩ | 40 | | | |
| | /e | Gain | GRP | 0.9 | 3.9 | 6.9 | dB | 40 | $S_1=2, V_T=-20dBV$ | Fig.12 | |
| | Receive | Maximum output | VRP | 1 | 5 | _ | dBV | 20 | S ₁ =2, THD=5% | | |
| ric tr | ď | Input impedance | ZRIN | 8.3 | 11.3 | 14.3 | kΩ | 40 | | | |
| Piezoelectric | | Gain | Gктр | 25.1 | 28.1 | 31.1 | dB | 40 | S ₁ =2, S ₂ =3 V _{KT} =-40dBV | Fig.12 | |
| | кт | Maximum output | Vктр | 1 | 5 | _ | dBV | 20 | S ₁ =2, S ₂ =3 THD=5% | | |
| | | Input impedance | Zĸτ | 11 | 15 | 19 | kΩ | 40 | | | |
| mit | | Gain | Сміс | 19.6 | 22.6 | 25.6 | dB | 40 | V _M =-40dBV | Fig.13 | |
| | міс | Maximum output | Vміс | 0 | 4 | _ | dBV | 20 | THD=5% | | |
| | | Input impedance | Zмic | 5 | 7 | 9 | kΩ | 40 | | | |
| Transmit | MF | Gain | Gмғ | 21.1 | 24.1 | 27.1 | dB | 40 | S ₂ =3, V _D =-40dBV | Fig.13 | |
| - | | Maximum output | VMF | 0 | 4 | _ | dBV | 15 | S ₂ =3, THD=5% | | |
| | | Input impedance | ZMF | 9 | 12 | 15 | kΩ | 40 | | | |
| Mute ratio * | | | MRRD | 30 | 35 | _ | dB | 40 | V _T =-20dBV S ₂ =1→3 | - Fig.12 | |
| | | | MRRP | 30 | 35 | _ | dB | 40 | V _T =-20dBV S ₂ =1→3, S ₁ =2 | | |
| | | | МВміс | 60 | 67 | _ | dB | 40 | V _M =-40dBV S ₂ =1→3 | - Fig.13 | |
| | | | MRMF | 60 | 67 | _ | dB | 40 | V _D =-40dBV S ₂ =3→1 | | |
| | | | ∆Grd | _ | -6 | _ | dB | _ | See Fig. 14 | Fig.14 | |
| Attenuation during branch | | ΔGRP | _ | -5 | _ | dB | _ | See Fig. 14 | | | |
| | | | Δ С міс | _ | -15 | _ | dB | _ | See Fig. 14 | | |
| Noise level | | | NRD | _ | —75 | _ | dBV | 120 | V _T =0 | Fig.12 | |
| | | | NRP | _ | -73 | _ | dBV | 120 | S ₁ =2, V _T =0 | | |
| | | | Иміс | _ | -74 | _ | dBV | 120 | V _M =0 | Fig.13 | |
| | | | NMF | _ | —71 | _ | dBV | 120 | S ₂ =3, V _D =0 | | |

^{*} When using 1 kHz bandpass filter

Electrical characteristic curves

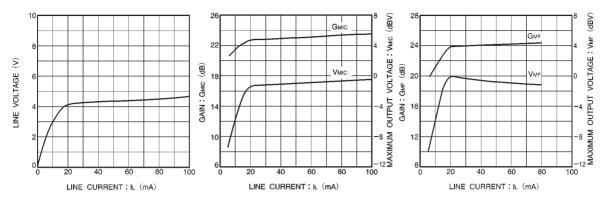


Fig. 1 Line voltage vs. line current

Fig. 2 MIC Line current

Fig. 3 MF Line current

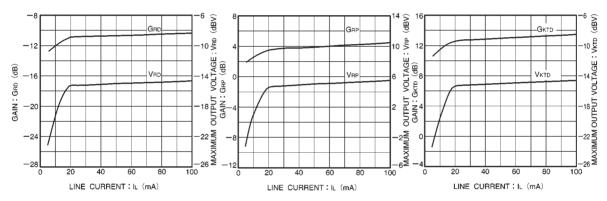


Fig. 4 Electromagnetic receiving Line current

Fig. 5 Piezoelectric receiving Line current

Fig. 6 Electromagnetic KT Line current

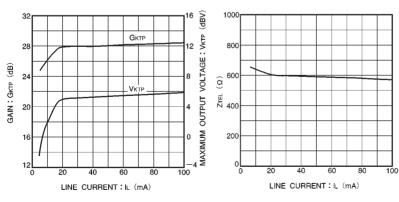


Fig. 7 Piezoelectric KT Line current

Fig. 8 AC impedance Line current

Measurement circuits

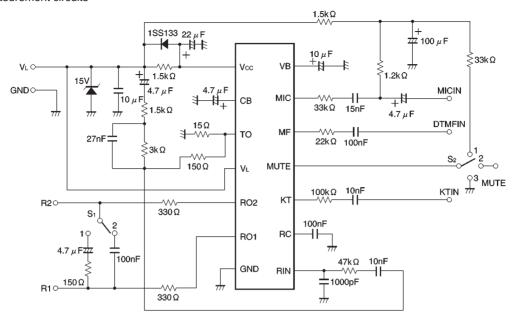


Fig. 9 Basic measurement circuit

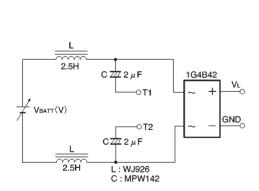


Fig. 10 Trunk circuit

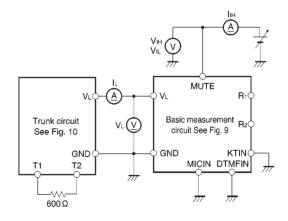


Fig. 11 DC characteristics measurement circuit

Communication ICs BA8216

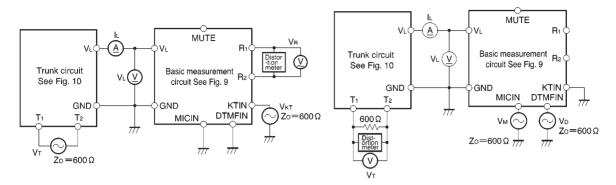


Fig. 12 Reception system measurement circuit

Fig. 13 Transmission system measurement circuit

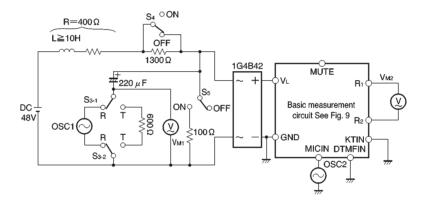


Fig. 14 Branch measurement circuit

Measurement method (MUTE = HIGH)

- (1) Reception
- 1) Set S_3 to R and S_4 and S_5 to OFF, and input a 1kHz signal from OSC1. Adjust to -10dBV if V_{M2} is piezoelectric, and to -30dBV if V_{M2} is electromagnetic.
- 2) With S₄ OFF and S₅ ON, record the output level of V_{M2} and note this value as V_{M2} (2).
- 3) With S_4 ON and S_5 ON, measure the output level of V_{M2} , and note this value as V_{M2} (3).

 $\Delta G_R = 20log (V_{M2} (3)/V_{M2}(2))$

- (2) Transmission
- 1) Set $S_3 = T$ and S_4 and S_5 to OFF, input a 1kHz signal from OSC2, and adjust so that V_{M1} is -10dBV.
- 2) With S₄ OFF and S₅ ON, record the output level of V_{M1} and note this value as V_{M1} (2).
- 3) With S_4 ON and S_5 ON, measure the output level of V_{M1} , and note this value as V_{M1} (3).

 Δ GMIC = 20log (V_{M1} (3)/V_{M1}(2))

S₃: Send and receive switch (reception side)

S₄: ON/OFF switch for line resistance (1300 Ω) (OFF)

S₅: ON/OFF switch for parallel resistance (100Ω) (OFF)

Circuit opperation

The BA8216 carries out the following basic operations.

(1) Handset talk and receive

The BA8216 receives a voice signal from a telephone line and outputs it to a handset speaker. It also takes a voice signal from the handset microphone and outputs it to the telephone line.

(2) DTMF send and key tone input

The BA8216 has a mute switch which can be switched between a "handset send and receive" mode and a "DTMF send and key tone input" mode by an external logic signal. In the "DTMF send and key tone input" mode, it transmits DTMF signals from the dial pad to the telephone line, and key tones to the handset receiver.

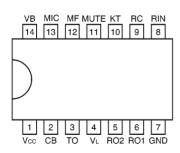
Operation notes

The maximum power dissipation for the BA8216 is 900mW. Since the maximum power dissipation varies with temperature, the product of the applied voltage V_L and the total current drawn by the IC, after factoring in the temperature, should not exceed the maximum dissipation.

Pin descriptions

| Pin No. | Symbol | Name | Function |
|---------|-----------------|---|--|
| 1 | Vcc | Internal power supply pin | Internal power supply pin. Power is supplied from V _L through resistor R ₁₀₁ , and is smoothed by capacitor C ₁₀₁ . |
| 2 | СВ | Bypass capacitor connector pin | This is used to connect an AC bypass capacitor to form a DC feedback loop for stabilizing the DC potential of the V _L pin. |
| 3 | то | Transmit/power dissipation resistor connector pin | This is connected between the power dissipation resistor R_{105} and the GND,to eliminate unnecessary power consumption. At the same time, R_{105} determines the gain of the final output stage of the transmission driver. R_{104} and R_{105} form two legs of the side tone suppression bridge, which is also connected to this pin. |
| 4 | VL | V _L pin | This is the power supply pin. The transmit signal is output to the telephone line through this pin. It is connected to the (+) side of the diode bridge. |
| 5 | RO ₂ | Receive output pin | When a piezoelectric receiver is used, connect a 330- protection resistor R_{191} to this pin. When a dynamic receiver is used, R_{191} may be 0Ω . |
| 6 | RO ₁ | Receive output pin | When a piezoelectric receiver is used, connect a 330- protection resistor R ₁₀₆ to this pin. C ₁₉₁ is shorted. When a dynamic receiver is used, a 4.7 μF DC blocking capacitor (C ₁₉₁) is connected in series with the 680 Ω resistor (R ₁₀₆) to this pin. |
| 7 | GND | Ground pin | This pin has the lowest potential on the IC. It is connected to the (—) pin of the diode bridge. |
| 8 | RIN | Receive input pin | After passing through a side tone suppression circuit, the receive signal frothe telephone line is input to this pin. |
| 9 | RC | Receive amplifier bypass capacitor pin | This is connected to the AC bypass capacitor of the reception amplifier. |
| 10 | KT | Key tone input pin | When the MUTE pin is low, key tone signals input on this pin are transmitted to the handset speaker. |
| 11 | MUTE | Mute input pin | When this is high, hand-set transmission is normal. When this is low, DTMF signals applied at the MF input are output to the telephone line, and key tones applied to the KT pin are transmitted to the hand receiver. |
| 12 | MF | DTMF signal input pin | When the MUTE pin is low, DTMF signals input to this pin are output to the telephone line. |
| 13 | MIC | Microphone input pin | Used to input signals from the microphone. |
| 14 | VB | Bias pin | This is the IC internal bias pin. It is connected to the bypass capacitor C ₁₁₁ . |

Pin assignments



Mute control input logic

| MUTE | MIC AMP | MF AMP | REC AMP | KT AMP | |
|------|---------|--------|---------|--------|--|
| Н | ON | OFF | ON | OFF | |
| L | OFF | ON | OFF | ON | |

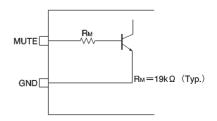


Fig. 15 Mute input equivalent circuit

Application example

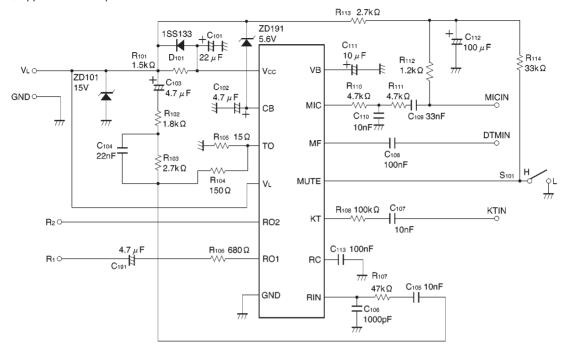


Fig. 16

External dimensions (Units: mm)

